imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



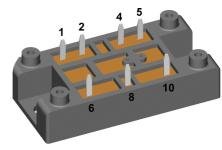
Standard Rectifier Module

3~ Rectifier Bridge

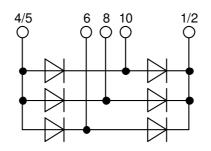
Part number

VUO34-16NO1

| 3~ Rectifier | | | |
|-----------------------------|---|------|--|
| $V_{\rm RRM}$ | = | 1600 | |
| $\mathbf{I}_{\mathrm{dav}}$ | = | 45 | |
| \mathbf{I}_{FSM} | = | 300 | |



Backside: isolated **E**72873



Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- · Very low leakage current

Applications:

- Diode for main rectification
- For three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: V1-A-Pack

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Height: 17 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

Terms Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact the sales office, which is responsible for you. Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact the sales office, which is responsible for you. Should you intend to use the product in aviation, in health or live endangering or life support applications, please notify. For any such application we urgently recommend

to perform joint risk and quality assessments;
the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

IXYS reserves the right to change limits, conditions and dimensions.

Data according to IEC 60747and per semiconductor unless otherwise specified

20151102c

VUO34-16NO1

LIXYS

VUO34-16NO1

| Rectifier | | | | | | Ratings | | | | |
|---------------------|-----------------------------------|----------------------------|---------------------------------|------|------|---------|------------------|--|--|--|
| Symbol | Definition | Conditions | | min. | typ. | max. | Unit | | | |
| V _{RSM} | max. non-repetitive reverse bloc | king voltage | $T_{VJ} = 25^{\circ}C$ | | | 1700 | V | | | |
| V _{RRM} | max. repetitive reverse blocking | voltage | $T_{VJ} = 25^{\circ}C$ | | | 1600 | V | | | |
| I _R | reverse current | $V_{R} = 1600 V$ | $T_{VJ} = 25^{\circ}C$ | | | 20 | μA | | | |
| | | $V_{R} = 1600 V$ | $T_{vJ} = 150^{\circ}C$ | | | 1 | mA | | | |
| V _F | forward voltage drop | I _F = 15 A | $T_{VJ} = 25^{\circ}C$ | | | 1,13 | V | | | |
| | | I _F = 45 A | | | | 1,46 | V | | | |
| | | I _F = 15 A | $T_{VJ} = 125 ^{\circ}C$ | | | 1,06 | V | | | |
| | | $I_F = 45 \text{ A}$ | | | | 1,48 | V | | | |
| DAV | bridge output current | T _c = 110°C | $T_{vJ} = 150 ^{\circ}\text{C}$ | | | 45 | Α | | | |
| | | rectangular d = ⅓ | | | | | 1 | | | |
| V _{F0} | threshold voltage | | T _{vJ} = 150°C | | | 0,81 | V | | | |
| r _F | slope resistance } for power | loss calculation only | | | | 14,9 | mΩ | | | |
| \mathbf{R}_{thJC} | thermal resistance junction to ca | ase | | | | 1,7 | K/W | | | |
| R _{thCH} | thermal resistance case to heats | sink | | | 0,4 | | K/W | | | |
| P _{tot} | total power dissipation | | $T_c = 25^{\circ}C$ | | | 70 | W | | | |
| I _{FSM} | max. forward surge current | t = 10 ms; (50 Hz), sine | $T_{VJ} = 45^{\circ}C$ | | | 300 | Α | | | |
| | | t = 8,3 ms; (60 Hz), sine | $V_{R} = 0 V$ | | | 325 | Α | | | |
| | | t = 10 ms; (50 Hz), sine | T _{vJ} = 150°C | | | 255 | Α | | | |
| | | t = 8,3 ms; (60 Hz), sine | $V_{R} = 0 V$ | | | 275 | Α | | | |
| l²t | value for fusing | t = 10 ms; (50 Hz), sine | $T_{vJ} = 45^{\circ}C$ | | | 450 | A ² s | | | |
| | | t = 8,3 ms; (60 Hz), sine | $V_{R} = 0 V$ | | | 440 | A ² s | | | |
| | | t = 10 ms; (50 Hz), sine | $T_{vJ} = 150 ^{\circ}\text{C}$ | | | 325 | A ² s | | | |
| | | t = 8,3 ms; (60 Hz), sine | $V_{R} = 0 V$ | | | 315 | A²s | | | |
| C | junction capacitance | V_{R} = 400 V; f = 1 MHz | $T_{vJ} = 25^{\circ}C$ | | 11 | | pF | | | |

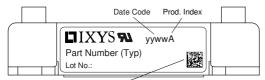
IXYS reserves the right to change limits, conditions and dimensions.

20151102c

LIXYS

VUO34-16NO1

| Package V1-A-Pack | | | | | Ratings | | | |
|----------------------|--------------------------------------------------------------|--------------|-----------------------------|------|---------|------|------|--|
| Symbol | Definition | Conditions | | min. | typ. | max. | Unit | |
| I _{RMS} | RMS current | per terminal | | | | 100 | А | |
| T _{vj} | virtual junction temperature | | | -40 | | 150 | °C | |
| T _{op} | operation temperature | | | -40 | | 125 | °C | |
| T _{stg} | storage temperature | | | -40 | | 125 | °C | |
| Weight | | | | | 37 | | g | |
| MD | mounting torque | | | 2 | | 2,5 | Nm | |
| d _{Spp/App} | creepage distance on surface striking distance through air | | terminal to terminal | 6,0 | | | mm | |
| d _{Spb/Apb} | | | terminal to backside | 12,0 | | | mm | |
| | isolation voltage | t = 1 second | | 3600 | | | V | |
| | t = 1 minute | | 50/60 Hz, RMS; liso∟ ≤ 1 mA | 3000 | | | V | |



Data Matrix: Typ (1-19), DC+Prod.Index (20-25), FKT# (26-31) leer (33), lfd.# (33-36)

| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | VUO34-16NO1 | VUO34-16NO1 | Blister | 24 | 461148 |

| Equivalent Circuits for Simulation | | | * on die level | T _{vJ} = 150 °C |
|------------------------------------|--------------------|-----------|----------------|--------------------------|
| | - Ro- | Rectifier | | |
| V _{0 max} | threshold voltage | 0,81 | | V |
| $\mathbf{R}_{0 \text{ max}}$ | slope resistance * | 13,7 | | mΩ |

20151102c

VUO34-16NO1

Outlines V1-A-Pack

1x45°

*11

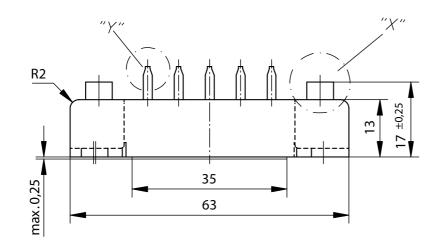
*0

*11

6

0,5

5,5



52 (see 1)

*0

+

*0

*7

€

=

*14

11,75 ±0,3 11,75 ±0,3

LC.

Marking on product Aufdruck der Typenbezeichnung

Ø0,8

12,2

5,5

 $* | \bigoplus |$

Ð

⊕

=

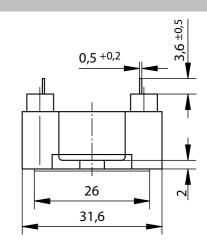
۴14

*14

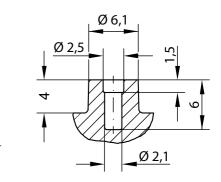
25

25,75 ±0,3

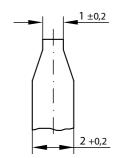
*7



Detail "X" M 2:1



<u>Detail "Y</u>" M 5:1



Remarks / Bemerkungen:

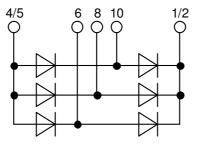
1. Nominal distance mounting screws on heat sink: 52 mm / Nennabstand Befestigungsschrauben auf Kühlkörper: 52 mm

*14

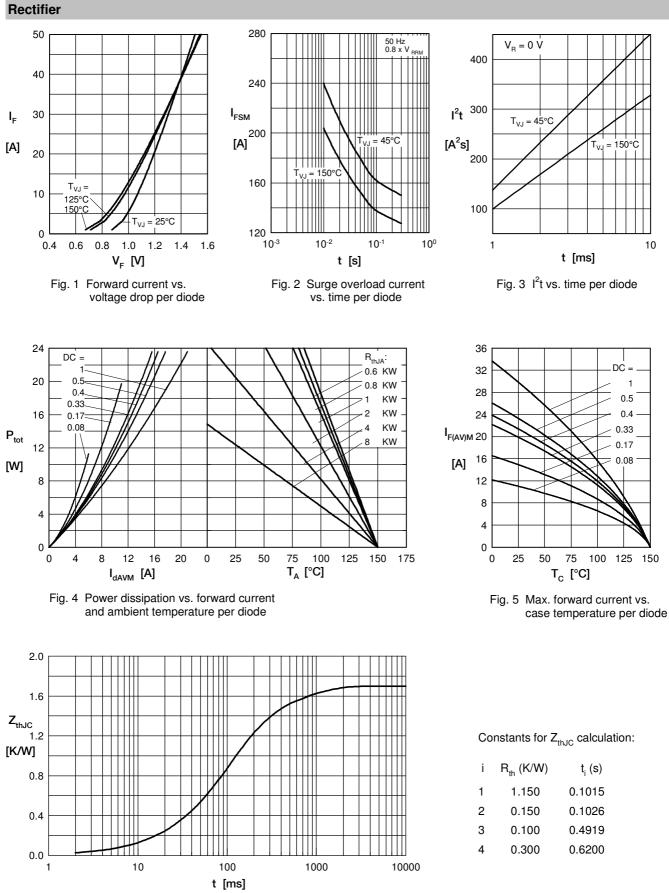
25

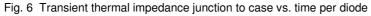
25,75 ±0,3

- General tolerance / Allgemeintoleranz: DIN ISO 2768 -11-c
 Surface treatment of pins: tin plated (Sn) in hot dip / Oberflächenbehandlung der Pins: verzinnt (Sn) im Tauchbad



LIXYS







Data according to IEC 60747and per semiconductor unless otherwise specified

20151102c